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	Substitute for fo	orm 1449A/B/PTO		PADEMIN	Application Number	10/811,979	
	INFORMATION DISCLOSURE				Filing Date	March 30, 2004	
	INFORMATION DISCLOSURE				First Named Inventor	KAMIYAMA	
	STATEMENT BY APPLICANT (Use as many sheets as necessary)				Group Art Unit	2814	
					Examiner Name	L. Pham	
	Chast	1	O.f	2	Attomory Docket Number	402019	

OTHER • NON PATENT LITERATURE DOCUMENTS Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item										
Examiner		include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number (s), publisher, city and/or country where published.								
Initials	Doc. No.									
i /2	D1	HOBBS, C. et al.; "Fermi Level Pinning at the PolySi/Metal Oxide Interface", 2003								
1 LP 1		HOBBS, C. et al.; "Fermi Level Pinning at the PolySi/Metal Oxide Interface", 2003 Symposium of VLSI Tech. Digest of Technical Papers, pp. 3-4.								

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Examiner Signature Date Considered 97/13/06

^{*} A concise statement of relevance is being submitted in lieu of a translation. 37 CFR 1.98(a)(3).